60614		
ROLL No.	-	

TEST BOOKLET No.

266

### TEST FOR POST GRADUATE PROGRAMMES

### **ELECTRONIC SCIENCE**

Time: 2 Hours

Maximum Marks: 450

#### INSTRUCTIONS TO CANDIDATES

- You are provided with a Test Booklet and an Optical Mark Reader (OMR) Answer Sheet to mark your responses. Do not soil the Answer Sheet. Read carefully all the instructions given on the Answer Sheet.
- 2. Write your Roll Number in the space provided on the top of this page.
- 3. Also write your Roll Number, Test Code, and Test Subject in the columns provided for the same on the Answer Sheet. Darken the appropriate bubbles with a Ball Point Pen.
- 4. The paper consists of 150 objective type questions. All questions carry equal marks.
- 5. Each question has four alternative responses marked A, B, C and D and you have to darken the bubble fully by a Ball Point Pen corresponding to the correct response as indicated in the example shown on the Answer Sheet.
- 6. Each correct answer carries 3 marks and each wrong answer carries 1 minus mark.
- 7. Space for rough work is provided at the end of this Test Booklet.
- 8. You should return the Answer Sheet to the Invigilator before you leave the examination hall. However, you can retain the Test Booklet.
- 9. Every precaution has been taken to avoid errors in the Test Booklet. In the event of any such unforeseen happenings, the same may be brought to the notice of the Observer/Chief Superintendent in writing. Suitable remedial measures will be taken at the time of evaluation, if necessary.

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### **ELECTRONIC SCIENCE**

1.	The unit of	of carrier	mobility in a	semiconductor i	S
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(A)	cm/	ν	 S
(4 )	61161	"	0

(B) 
$$cm^2/v-s$$

(C) 
$$cm^2/v$$

(D) 
$$cm^2/s$$

- (A) increases
- (B) decreases
- (C) remains constant
- (D) may increase or decrease depending upon the doping levels

3. The RMS value of a half wave rectified symmetrical square wave of 1A is

(A) 
$$\frac{1}{\sqrt{2}}$$
 A

(C) 
$$\sqrt{2}A$$

4. If 
$$\alpha$$
 of a BJT = 0.995 and  $I_{CO} = 0.5$  mA, then  $I_{CEO}$  will be

(A)  $100 \mu A$ 

(B)  $25\mu A$ 

(C)  $10.1\mu A$ 

(D) 10.5μA

- (A) fast turn on
- (B) fast turn off
- (C) large collector base reverse bias
- (D) large emitter base forward bias

6. A switched mode power supply operating over 20 kHZ to 100 kH range uses as the main switching element  (A) SCR (C) triac (D) MOSFET  7. The cardinal advantage of a bridge rectifier over a full wave rectifie using a centre-tapped transformer is  (A) lower peak inverse requirement (B) lower ripple factor (C) higher efficiency (D) that larger current can be delivered  8. The breakdown voltage of a BJT with its base open is BVCEO and that with emitter open is BVCEO. Then  (A) BVCEO < BVCBO (B) BVCEO = BVCBO (C) BVCEO > BVCBO (D) the voltage BVCEO and BVCBO are unrelated  9. The UJT is a  (A) voltage controlled device (B) current controlled device (C) relaxation oscillator (D) BJT  10. The lowest output impedance is obtained in case of  (A) CB configuration only (B) CE configuration only (C) both CB and CE configurations (D) CC configuration			
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(B) BVCEO = BVCBO (C) BVCEO > BVCBO (D) the voltage BVCEO and BVCBO are unrelated  9. The UJT is a  (A) voltage controlled device (B) current controlled device (C) relaxation oscillator (D) BJT  10. The lowest output impedance is obtained in case of  (A) CB configuration only (B) CE configuration only (C) both CB and CE configurations	8.	The breakdown voltage of a BJT with its base open is $BV_{CEO}$ an with emitter open is $BV_{CEO}$ . Then	d that
9. The UJT is a  (A) voltage controlled device (B) current controlled device (C) relaxation oscillator (D) BJT  10. The lowest output impedance is obtained in case of  (A) CB configuration only (B) CE configuration only (C) both CB and CE configurations		(B) $BV_{CEO} = BV_{CBO}$ (C) $BV_{CEO} > BV_{CBO}$	
10. The lowest output impedance is obtained in case of  (A) CB configuration only (B) CE configuration only (C) both CB and CE configurations	9.		
(A) CB configuration only (B) CE configuration only (C) both CB and CE configurations		Televation and III	ce
(B) CE configuration only (C) both CB and CE configurations	10.	The lowest output impedance is obtained in case of	
		(B) CE configuration only (C) both CB and CE configurations	



11.	Tunnel	diodes are fabricated from
	(A) (B) (C) (D)	silicon only germanium only either silicon or germanium either germanium or gallium arsenide
12.	N chan	nel FETs are superior to P channel FETs because
	(A) (B) (C) (D)	they have a higher input impedance they have larger switching time mobility of electrons is greater than that of holes they consume less power
13.	DIAC i	s a solid state device which works as a
	(A) (B) (C) (D)	2 terminal unilateral switch 2 terminal bidirectional switch 3 terminal bidirectional switch 4 terminal bidirectional switch
14.	A trans	istor is said to be in the quiescent state when
	(A) (B) (C) (D)	no signal is applied at the input it is unbiased no currents are flowing emitter junction bias is equal to the collector junction bias
15.	In the C	CE configuration the input and output signals are
	(A) (C)	always equal (B) in phase out of phase (D) always negative
16.	When increase	the positive voltage on the gate of a P channel JFET is ed, the drain current
*	(A) (C)	remains the same decreases (B) increases (D) fluctuates erratically

If the collector and emitter terminals of a BJT are interchanged, the  $\beta$ of the inverted mode will be (A) equal to  $\beta$  of normal mode (B) greater than  $\beta$  of normal mode

(C) less than  $\beta$  of normal mode

(D) zero

18. A transformer cannot be called an amplifier because it cannot give

> (A) current gain (B) voltage gain (C) gain at high frequencies (D) power gain

Solar cell is an example of 19.

(A) photoconductive device

(B) photoemissive device

(C) both photoconductive device and photoemissive device

(D) photovoltaic device

20. In a FET, the drain voltage above which there is no increase in drain current is called

(A) critical voltage

(B) pinchoff voltage

(C) breakdown voltage

(D) pick up voltage

21. In a JFET source follower,  $\mu = 200$ ,  $r_d = 20k\Omega$  and source load resistance  $R_L = 1k\Omega$ . The output resistance of the source follower is approximately

> (A)  $333\Omega$

(B) 500Ω

6000

(D)  $1k\Omega$  22. In a full wave rectifier using a centre tapped transformer RMS value of secondary voltage = 560V and load =  $2k\Omega$ . The RMS voltage across each diode is

(A) 2	V08.
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(B) 201.3V

(D) 790.7V

When two identical stages with upper cut off of  $\omega_H$  are cascaded, the overall 3 dB point is at

(A)  $\omega_H$ 

(B)  $0.5 \omega_{H}$ 

(C)  $2\omega_H$ 

(D)  $0.64 \, \omega_{H}$ 

24. Which one of the following can be achieved by using the reset terminals in a tuner chip?

(A) Keyed oscillations

(B) Delayed monostable action

(C) Square wave generation

(D) Pulse generation

25. A two stage amplifier with negative feedback has an overshoot when the damping factor is

(A) zero

(B) less than unity

(C) negative

(D) greater than unity

26. Which one of the following relations for a transistor is correct?

(A)  $h_{ie} = \frac{1 + h_{fb}}{h_{ib}}$ 

(B)  $h_{ie} = \frac{h_{ib}}{1 + h_{fb}}$ 

(C)  $h_{ie} = \frac{1 - h_{fb}}{h_{ib}}$ 

(D)  $h_{ie} = \frac{h_{ib}}{1 - h_{gh}}$ 

27. In a class C amplifier the output current is zero for

(A) half cycle

1

(B) full cycle

(C) less than half cycle

(D) more than half cycle



28.	A clas	ss B push pull amplifier suffe	rs fron	m
	(A) (B) (C) (D)	excessive harmonic distortion intermodulation distortion	tion	
29.	An oso	cillator of the LC type that ha	as a sp	lit capacitor in the tank circuit
	(A) (C)	3	(B) (D)	I am a a a a a a a a a a a a a a a a a a
30.	Clamp	er circuits are also known as		
	(A) (B) (C) (D)	AC restorer DC restorer voltage to frequency conve	rter rter	
31.	Freque	ncy multiplication can be obt	ained	by using
	(A) (C)	Class A amplifiers Class C amplifiers	(B) (D)	Class B amplifiers Class AB amplifiers
32.	The fee	edback network of a phase sh	ift osci	illator usually consists of
	(A) (C)	RC circuit LC circuit	(B) (D)	RL circuit None of the above
33.	CB amj	olifier is most suitable for use	in	
	(A) (B) (C) (D)	very high frequency circuits low frequency circuits medium frequency circuits low current circuits	3	

A loudspeaker is operated by



34.

•	(A)	anipilitici	(B) (D)	The second secon
35.	Which	of the following amplifiers	has lar	gest bandwidth?
	(A) (B) (C) (D)	Difference amplifier Transformer coupled amr	olifier	
36.	The p ground	otential difference betwee ed, is to be amplified. We	n two will use	points, neither of which is
	(A) (B) (C) (D)	RC coupled amplifier audio power amplifier difference amplifier transformer coupled ampl	lifier	
37.	The up	oper cut-off frequency of s on	an RC	coupled amplifier mainly
	(A) (B) (C) (D)	coupling capacitor cathode bypass capacitor output capacitance of the s interelectrode capacitance	ignal so and stra	urce y capacitance
38.	When th	ne emitter resistance is bypa		
	(A) (B) (C)	voltage gain is reduced voltage gain is increased thermal runaway is caused the Q-point is stabilised		
39.	To ampl we use	ify a RF signal containing	870 kH	Z, 875 kHZ and 880 kHZ,
	(A)	audio frequency amplifier tuned voltage amplifier	(B) (D)	wide band amplifier push-pull amplifier

(D) -5dB/octave

The term "free running" is usually associated with 41.

> bistable multivibrator (B) astable multivibrator monostable multivibrator (C) (D) Any of the above

When a PNP transistor is saturated 42.

> (A) base, emitter and collector are at the same potential emitter is at a higher potential than base and collector collector is at a higher potential than base and emitter (D) base is at a higher potential than emitter and collector

43. Crossover distortion is eliminated in a push-pull amplifier by

> (A) using a transformer with a large step down ratio (B) using a transformer with a large step up ratio (C) providing a small forward bias to the transistors (D) supplying both transistors with in phase signals

In a single stage RC coupled amplifier, the phase of the output with 44. respect to the input at very low and at very high frequencies approaches respectively

> (A) 135° and 225° (B) 90° and 270° (C) 270° and 90° (D) 90° and 180°

For which of the following configurations, does the input impedance of 45. the amplifier depend strongly on the load resistance?

> (A) CE (B) CC (C) CB (D) CE and CB

* 2	9
46.	In a RC coupled amplifier, the rate of change of voltage gain in the high frequency range is
	(A) -3dB/octave (B) -10dB/octave (C) -16dB/octave (D) None of the above
47.	The input to a push-pull amplifier contains components of 150 Hz, 300Hz, 450 Hz and 600 Hz. The output will contain
	(A) only 150 Hz (B) only 150 Hz and 450 Hz (C) only 300 Hz and 600 Hz (D) All the four components
48.	An important advantage of the RC coupling scheme is
	(A) economy (B) good frequency response (C) high efficiency (D) good impedance matching
49.	A Zener diode is primarly used for
	<ul> <li>(A) rectification</li> <li>(B) producing constant current</li> <li>(C) producing constant voltage</li> <li>(D) detection of audio signals in radio waves</li> </ul>
50.	The low frequency cut-off in an amplifier is due to
	<ul> <li>(A) only coupling capacitors</li> <li>(B) only bypass capacitors</li> <li>(C) both coupling and bypass capacitors</li> <li>(D) the internal transistor junction capacitances</li> </ul>
51.	The Boolean expression $\overline{x}$ $\overline{y}$ $z+yz+xz$ after minimisation becomes
	(A) $x$ (B) $y$ (C) $z$ (D) $x + y + z$
¥	

52.	The H	amming code 110	01101 has be	en rec	ceived. Fault ha	s occurred at
	(A) (C)	second portion fourth portion		(B) (D)	1	
53.	Extrem achieve	nely low power	dissipation	and	low cost per	gate can be
	(A) (C)			(B) (D)	CMOS ICs ECL ICs	
54.	Which	of the following	digital IC far	milies	gives the maxim	num fan-out?
	(A) (C)	ECL		(B) (D)	PMOS CMOS	
55.	An exa	mple of a univer	sal logic gate	is		
	(A) (C)	AND NOT		(B) (D)	OR NOR	
56.	A posit	ive logic AND g	ate is the sam	ne as a	a negative logic	
	(A) (C)	OR gate NAND gate		(B) (D)	AND gate NOR gate	
57.	An exa	mple of a weight	ed self-comp	lemer	nting code is	
	(A) (C)	8421 code 8421 code		(B) (D)	7421 code Gray code	
58.	An exa	mple of a binary	number whic	h is e	qual to its 2's co	omplement is
	(A) (C)	0000 0001		(B) (D)	1000 1111	

	11
59.	The octal equivalent of decimal 0.3125 is
	(A) 0.16 (C) 0.24 (B) 0.26 (D) 0.124
60.	An example of a 16 bit $\mu p$ is
	(A) Zi log 80 (B) 8085 (C) Motorola 6800 (D) 8086
61.	Which one of the following A/D converters utilises a logic programmer?
	<ul> <li>(A) Dual slope A/D converter</li> <li>(B) Continuous balance type A/D converter</li> <li>(C) Successive approximation A/D converter</li> <li>(D) Stair case ramp type A/D converter</li> </ul>
62.	The ASCII code is
	(A) an error detecting code (C) an alphanumeric code (B) a self correcting code (D) a weighted code
63.	Module – 2 addition is represented by
	(A) $\overline{x} y + x \overline{y}$ (B) $xy + \overline{x} \overline{y}$ (C) $x + \overline{x} y$ (D) $xy + \overline{x} z + yz$
64.	Which one of the following is correct?
	(A) $\overline{x} \overline{y} z + y z + x z = \overline{y} z + x z$ (B) $\overline{x} y z + y z + x z = x y + \overline{x} z$ (C) $xy + \overline{x} z = x y + \overline{x} z + y z$ (D) $x + \overline{x} y = x y$
65.	SN 7410 IC is a
	(A) quad 2 input NAND gate (B) triple 3 input NAND gates (C) dual m/s JK flip-flops (D) multiplexer

66.	The primary data pointers of 8085 are		
	(A) (C)	registers B and C (E registers H and L (D	B) registers D and E D) registers B and D
67.	The va	lue of the most significant be on of an instruction by 8085 is st	it of the result following the cored in
	(A) (C)	carry status flag sign status flag (D	) auxiliary carry status flag ) zero status flag
68.	The 808 needed	80 $\mu p$ has an instruction set of should be at least	91 instructions. The op-code
	(A) (C)	6 bits long (E 7 bits long (C	,
69.	Which	memory does a microprogramm y unit?	ed computer have in its control
	(A) (C)		Semiconductor RAM  None of the above
70.	The pho	otomasking process during fabric	cation of ICs
	(A) (B)	A	of impurities prevents diffusion in selected
	(C) (D)	is used to remove selected area is used for removal of photores	
71.	The bas	sic RS flip-flop is a	
	(A) (C)	· ·	monostable multivibrator     free running multivibrator
		Also ferr	



72.	In a pos	sitive logic system a logic 1 r	eprese	ents
	(A) (B) (C) (D)	zero voltage  -1 volts  more negative of the two vo  more positive of the two vo		
73.	The inp	ut impedance of an OP-AMI	Pis	
	(A) (C)	zero very high but not infinite	(B) (D)	small infinite
74.	The equ	nivalent decimal number for	Gray o	ode 1011 is
	(A) (C)	14 41	(B) (D)	13 31
75.	The out	put of an OP-AMP is	e.	
	(A) (B) (C) (D)	90° out of phase with the in -90° out of phase with the 45° out of phase with the in 180° out of phase from the	input put	
76.		gain of a chopper amplifier then the DC gain of the cho		00 and the OP-AMP gain is abilised OP-AMP will be
, "	(A) (C)	50,000 50	(B) (D)	1000 50×10 <sup>6</sup>
77.		of the following memories as of the memory unit?	has g	ot equal access time for all
	(A) (C)	ROM RAM	(B) (D)	PROM ERAM

78.

A source programme is translated into machine language by



	(A) (C)	programmer compiler	(B) (D)	operator card reader
79.	MSI cir	reuit usually contains		
	(A) (C)	less than 10 gates more than 100 gates	(B) (D)	10 to 100 gates 1000 gates
80.	LSI circ	cuits usually contain		
	(A) (C)	less than 10 gates more than 100 gates	(B) (D)	10 to 100 gates more than 1000 gates
81.	For buil	ding a decode counter, the		
	(A) (C)	4	(B) (D)	5
82.	The char	racteristic equation of a T i	lip-flop i	S
83.	(C)	$Q_{N+1} = \overline{T}Q_N + T\overline{Q}_N$ $Q_{N+1} = \overline{T}Q_N$ occessor must necessarily h	(D)	$Q_{N+1} = TQ_{N}$ $Q_{N+1} = \overline{TQ}_{N}$
	(A) (B) (C)	data bus data bus and address bus control bus data bus, control bus and a		bus
34.	How mu access?	ch of memory a μp with	h a 12 b	it address bus be able to
*	(A) 1 (C) 8	KB KB		KB 4 KB
•				

85.	Which o	of the following flag condit	tions are	e not available in 8085?
	(A) (C)	Zero flag Overflow flag	(B) (D)	Parity flag Auxiliary carry flag
86.	The freq of a 808.	uency of the driving netw 5 must be	ork con	nected between pins 1 and 2
	(B)	twice the desired clock fre equal to the desired clock if four times the desired cloc half of the desired clock fr	frequenc k freque	ency
87.	A high or	RESET OUT line signifi	es that	
•	(C) a	all of the registers of the Call the registers and countered the registers and countered the registers and countered to reprocessing can begin when	rs are be ers are eset the	being reset and in addition
88.		5 instruction MOV r.		s the following mode of
		egister direct		immediate relative
89.	READY s	ignal in 8085 is useful wh	en the C	CPU communicates with
	(A) a (C) a	slow peripheral chip n OMA controller chip		a fast peripheral chip a PPI chip
90.	Which of	the following tools :-	6	

following tasks is not performed by an assembler?

(A) Providing a storage allocation

(B) Creating a table of labels etc.
(C) Doing assembly time arithmetic

(D) Translate a programme written in high level language to machine code programme

91.	Which of the following instructions copies a byte of data into the accumulator from the memory address given in the instruction?							
	(A) LDA address (B) LDA×B (C) LHLD address (D) STA address							
92.	A DAD H instruction is	same as						
	(B) shifting each bit (C) shifting each bit LSB position	one position to the left one position to the right one position to the left with a zero inserted in						
	(D) shifting each bit in MSB position	one position to the right with a zero inserted						
93.	In an ORA r instruction							
	<ul> <li>(A) zero flag is set</li> <li>(B) auxiliary carry fl</li> <li>(C) carry flag is set</li> <li>(D) None of the flags</li> </ul>							
94.	Return from a subroutine	is affected by						
	(A) a jump instruction (C) a RET instruction							
95.	PSW stands for							
	<ul><li>(A) accumulator con</li><li>(B) flag byte</li><li>(C) accumulator and</li><li>(D) accumulator and</li></ul>							
96.	Which of the following interface?	control signal does not belong to printer						
	(A) DAV (C) NEW LINE ACI	(B) DACC (D) TRACK OO						
<b>v</b> .								



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97.	not IBM compatible?							
	(A) (C)	Single density single side Single density double side	(B) (D)	2 0				
98.	A USA	JSART chip provides						
	(A) (B) (C) (D)	half duplex operation full duplex operation diplex operation full duplex operation, but ca	annot	work in asynchronous mode				
99.	The cal	ibration signal available fron	ı a CR	O is of				
	(A) (C)	square waveshape sinusoidal waveshape	(B) (D)	sawtooth waveshape Any of the above				
100.	The inp	The input impedance of an oscilloscope must be						
	(A) (C)	low inductive	(B) (D)	high capacitive				
101.	To double the current range of a $50\mu A$ , $2000\Omega$ meter movement, the shunt resistance required is							
	(A) (C)	40Ω 2000Ω	(B) (D)	50Ω 25Ω				
102.	The purpose of the INT/EXT switch in a CRO is to							
	<ul> <li>(A) select the input to SYNC control</li> <li>(B) provide an internal signal to the vertical input</li> <li>(C) select inputs to the horizontal terminals</li> <li>(D) None of the above</li> </ul>							



- 18 Two sinusoids of peak amplitude ratio 1:2 differing in phase by 90° give a Lissajo's pattern as (A) straight line in first and third quadrants (B) straight line in second and fourth quadrants (C) ellipse (D) circle A transformer with a 20:1 voltage step down ratio has 6V across  $0.6\Omega$
- in the secondary. Is and Ip are given by
  - (A) 10A, 5A (B) 5A, 10A (C) 10A, 0.5A (D) 1A, 0.5A
- A voltmeter utilises a  $20\mu A$  meter movement. The sensitivity of the 105. voltmeter is
  - (A) 1000Ω/V (B) 20000Ω/V (C) 50kΩ/V (D) 10 micro ohms per volt
- The scale used for moving coil meter is 106.
  - (A) a nonlinear scale (B) a linear scale (C) a square scale (D) a log scale
- Maximum input frequency = f and chopping frequency = F. In a chopper amplifier
  - (A) F > 10f(B) F < 0.1f(C) F = 2f(D) F = 0.5 f
- Damping ratio =  $\delta$  and rise time =  $t_r$ . If the bandwidth of a system is 108.
  - (A) both  $\delta$  and  $t_r$  increase
  - (B)  $\delta$  decreases but  $t_r$  increases
  - (C)  $\delta$  increases but  $t_r$  decreases
  - (D) both  $\delta$  and  $t_r$  decrease

- 109. An amplitude detector detects
  - (A) the peak value of the modulation signal
  - (B) the envelope of the modulating signal
  - (C) the peak value of the carrier signal
  - (D) the average value of the carrier signal
- 110. Microwave links are generally preferred to co-axial cable for TV transmission because
  - (A) they have less overall phase distortion
  - (B) they are cheaper
  - (C) of their greater bandwidth
  - (D) of their relative immunity to impulse noise
- 111. In amplitude modulation, the magnitude of the sidebands is  $(m_a = \text{modulation index})$ 
  - (A)  $m_a$  times the carrier amplitude
  - (B)  $2m_a$  times the carrier amplitude
  - (C)  $m_a/2$  times the carrier amplitude
  - (D)  $m_a/4$  times the carrier amplitude
- 112. Sinusoidal carrier voltage of frequency 1 MHz is amplitude modulated by a band of frequencies from DC to 5 kHZ. The frequency of the upper sideband and lower sideband will be
  - (A) 1005 kHZ and 1000 kHZ
- (B) 1010 kHZ and 990 kHZ
- (C) 1005 kHZ and 995 kHZ
- (D) 1500 kHZ and 995 kHZ
- 113. The RMS value of the antenna current is 5A before modulation and it increases to 5.8A after amplitude modulation. The percentage of modulation index is
  - (A) 88%

(B) 80%

(C) 83.14%

(D) 81.21%



- In FM demodulation, Foster-Seely discriminator uses a 114.
  - (A) single tuned circuit
  - double tuned circuit in which primary and secondary are tuned to different frequencies
  - (C) double tuned circuit in which primary and secondary are tuned to the same frequency
  - (D) combination of two transistors in push-pull operation
- Polarised relays
  - can distinguish between the two directions of current flow through their coil windings
  - (B) cannot distinguish between the two directions of current flow through their coil windings
  - (C) cannot operate at high speed
  - (D) can be used as smallest element of signaling code
- Simplex circuit is one in which
  - (A) two messages are transmitted by one station and received by the other simultaneously over the same line
  - only one message is sent at a time over a line
  - one character of a word is transmitted independently of
  - (D) two messages are sent in opposite directions simultaneously over the same line
- The channel capacity of a band limited Gaussian channel is given by 117.

(A) 
$$C = B \log_2\left(2 + \frac{S}{N}\right)$$
 (B)  $C = B \log_2\left(1 + S/N\right)$ 

(B) 
$$C = B \log_2(1 + S/N)$$

(C) 
$$C = B \log_{10} (1 + S/N)$$
 (D)  $C = B \log_{c} (1 + S/N)$ 

(D) 
$$C = B \log_{10} (1 + S/N)$$



If x and y are independent Gaussian random variables each with 118. average value zero and with same variance, their joint probability density function is given by

(A) p(x,y) = p(x+y) (B) p(x,y) = p(x)p(y)

(C) p(x,y) = p(x) + p(y) (D) p(x,y) = p(x) + p(x)p(y)

In a random ergodic communication process 119.

(A) ensemble and time averages are different

(B) ensemble and time averages are same

(C) ensemble and time averages are opposite to each other

(D) None of the above

120. Fidelity in a communication receiver is provided by

(A) audio stage

(B) mixer stage

(C) detector stage

- (D) combination of audio and detector stages
- EM waves are refracted when they

(A) pass into a medium of different dielectric constant

(B) are polarised at right angles to the direction of propagation

(C) encounter a perfectly conducting medium

(D) pass through a small slot in a conducting medium

Tropospheric scalter is used for communication in the frequency range 122.

(A) HF

(B) VHF

(C) UHF

(D) VLF

22 Line of sight transmission is a characteristic of propagation for (A) VHF only (B) VHF and UHF (C) low radio frequencies below 1MHz (D) AM picture signal but not FM sound signal 124. When a line of any odd multiple of a quarter wavelength is short circuited, it represents (A) infinite impedance (B) zero impedance (C) unity impedance (D) characteristic impedance Zo Ungrounded antenna near the ground 125. (A) acts as an antenna array (B) acts as a single antenna of twice the height (C) must be vertically polarised (D) must be horizontally polarised For matching purposes, tapers are preferred to transformers because of 126. (A) ease of fabrication (B) low cost (C) durability (D) low loss A crystal which has a sensitivity of -55 dBm with a 1 MHz BW amplifier, will have a sensitivity with 4 MHz BW amplifier equal to (A) -55 dBm (B) -52 dBm(C) +58 dBm (D) 52 dBm 128. A helical antenna is used for satellite because of its

(C) good front to back ratio (D) None of the above

(B) broad bandwidth

(A) circular polarisation

129.	In	a	TV	transmission	system
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- (A) the picture is AM and sound is FM
- (B) the picture is FM and sound is AM
- (C) both the picture and the sound are AM
- (D) both the picture and the sound are FM

# 130. Delhi TV is transmitting on channel 4. For this channel, the carrier frequency for the picture is

(A) 60 MHz

- (B) 62.25 MHz
- (C) 67.7 MHz
- (D) 68.5 MHz

### 131. When an EM wave is propagated in a waveguide

- (A) they travel along the broader walls of the guide
- (B) they are reflected from the walls but do not travel along them
- (C) they travel through the dielectric without touching the wall
- (D) None of the above

# 132. The wavelength of an EM wave in waveguide

- (A) is directly proportional to phase velocity
- (B) is inversely proportional to phase velocity
- (C) is greater than that in free space
- (D) depends only on the waveguide dimensions and the free space wavelength
- 133. In an AM wave,  $V_{\text{max}} = 10V$  and  $V_{\text{min}} = 5V$ . The percentage of modulation is
  - (A) 2

(B) 33.3

(C) 50

(D) 100

(A) LG = RC

(B) LC = GR

(C) LR = R

(D) LR = G

135.	VSWI	on a transmission line is always
	(A) (C)	D) less than or equal to 1
136.	If band will	dwidth of an amplifier is reduced, thermal noise in the amplifier
	(A) (C)	increase not be affected  (B) decrease (D) become random in nature
137.	The sig	mal to noise ratio at the input of an amplifier can be improved
	(A) (B) (C)	by decreasing the source impedance
138.	The col	our of light emitted by an LED depends on
	(A) (B) (C) (D)	forward bias
139.	Bulk typ	pe photoconductive cells have
	(A) (B) (C) (D)	wide spectral response small response time high cost high dark to light resistance ratio

(A) operated in forward direction
(B) encased in an opaque package
(C) a very fast photodetector
(D) dependent on thermally generated minority carriers

A PN junction photodiode is

140.

- 141. Silicon is invariably used in the manufacture of junction photodiodes because
  - more electron hole pairs are generated (A)
  - thermally generated minority current is extremely small
  - Silicon is more rigged than Ge
  - (D) it needs less reverse bias
- A PIN photodiode has ultrafast response primarily due to 142.
  - (A) the presence of the middle I layer
  - (B) heavy doping of P and N regions
  - higher electrical conductivity of silicon
  - (D) its wide spectral response
- The superposition theorem is essentially based on the concept of 143.
  - (A) duality

- (B) linearity
- (C) reciprocity
- (D) non-linearity
- 144 Thevenin resistance is found
  - (A) between any two open terminals
  - (B) by short-circuiting the given two terminals
  - (C) by removing voltage sources along with their internal resistances
  - (D) between same open terminals as for  $V_{th}$
- Norton's equivalent of a circuit consists of a 145.
  - (A) constant current source with a conductance in parallel
  - (B) constant current source in series with an infinite resistance
  - (C) constant voltage source in parallel with a high resistance
  - (D) single current source and a single voltage source



- 146. Two identical 3A, 4Ω Norton equivalent circuits are connected in parallel with like polarity to like. The combined Norton equivalent circuit is
  - (A) 6A,  $4\Omega$
- (B) 6A,  $2\Omega$
- (C)  $3A, 2\Omega$

- (D)  $6A, 8\Omega$
- 147. A step recovery diode
  - (A) has an extremely short recovery time
  - (B) conducts equally well in both directions
  - (C) is mainly used as a harmonic generator
  - (D) is an ideal rectifier of high frequency signals
- 148. A PIN diode is frequently used as a
  - (A) peak clipper
  - (B) voltage regulator
  - (C) harmonic generator
  - (D) switching diode for frequencies upto GHz range
- 149. Intermodal dispersion results from the fact that the light waves propagate through an optical fiber
  - (A) in different modes
- (B) along different routes
- (C) as a group of frequencies
- (D) with same velocity
- 150. An all plastic optical fiber is strong mechanically as compared to an all glass fiber but has
  - (A) higher losses
  - (B) lower bandwidth
  - (C) lower tensile strength
  - (D) higher losses and lower bandwidth

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SPACE FOR ROUGH WORK



## SPACE FOR ROUGH WORK